

# CNC1S101, CNZ3132, CNZ3133, CNZ3134 (ON3131, ON3132, ON3133, ON3134)

## Optoisolators

### Overview

CNC1S101 is a DIL type 4-pin single-channel optoisolator which is housed in a small package. This optoisolator series also includes the two-channel CNZ3132, the three-channel CNZ3133, and the four-channel 3134.

The CNC1S101 series has a number of good features, including high I/O isolation voltage and current transfer ratio (CTR), as well as high speed response.

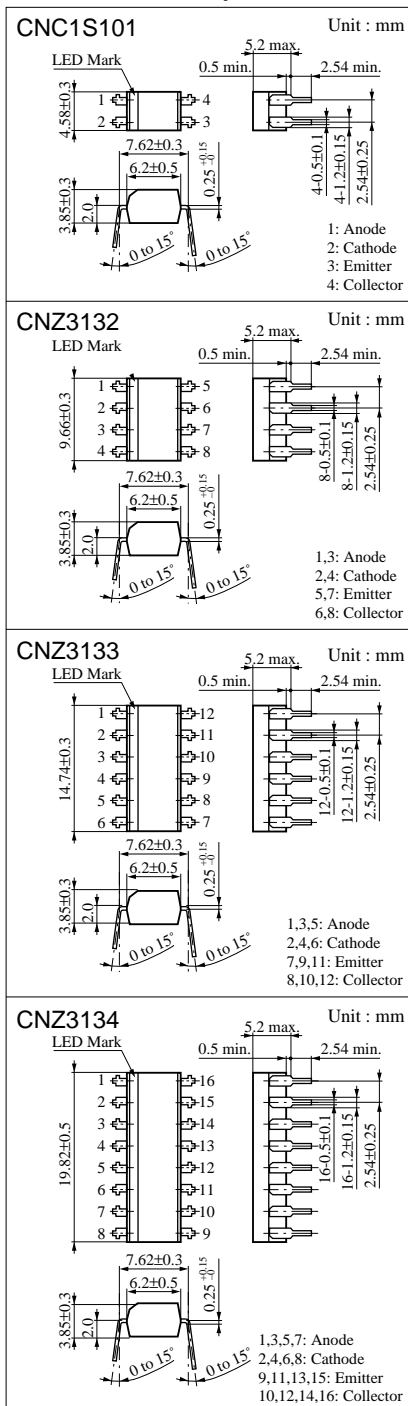
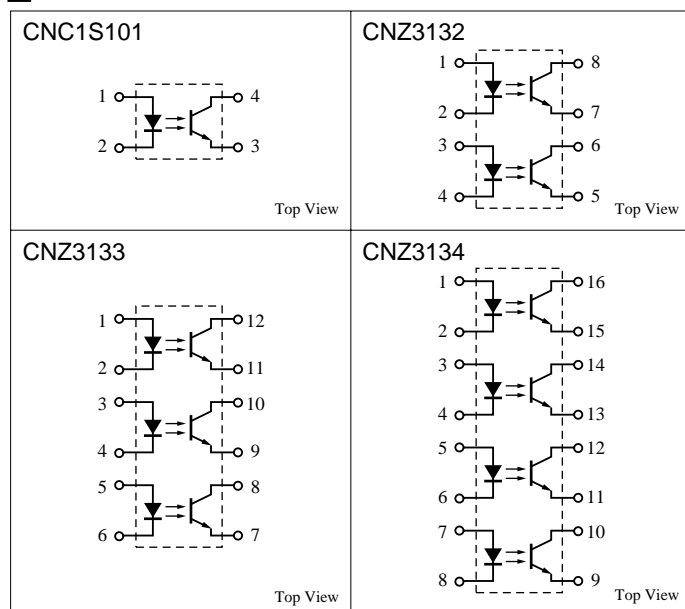
### Features

- High current transfer ratio :  $CTR \geq 100\%$
- High I/O isolation voltage :  $V_{ISO} = 5000 V_{rms}$  (min.)
- Fast response :  $t_r = 2 \mu s$ ,  $t_f = 3 \mu s$  (typ.)
- Low dark current :  $I_{CEO} \leq 100 nA$
- UL listed (UL File No. E79920)

### Applications

- Switching power supply
- Computer terminal equipment
- System equipment, measuring equipment
- Telephones, copier, vending machines
- Televisions, VCRs, and other consumer electronics products
- Medical equipment and physical and chemical equipment
- Signal transmission between circuits with different potentials and impedances

### Pin Connection



Note) The part numbers in the parenthesis show conventional part number.

### ■ Absolute Maximum Ratings (Ta = 25°C)

Parameter		Symbol	Ratings	Unit
Input (Light emitting diode)	Reverse voltage (DC)	$V_R$	6	V
	Forward current (DC)	$I_F$	50	mA
	Pulse forward current	$I_{FP}^{*1}$	1	A
	Power dissipation	$P_D^{*2}$	75	mW
Output (Photo transistor)	Collector current	$I_C$	50	mA
	Collector to emitter voltage	$V_{CEO}$	80	V
	Emitter to collector voltage	$V_{ECO}$	7	V
	Collector power dissipation	$P_C^{*3}$	150	mW
Total power dissipation		$P_T$	200	mW
Operating ambient temperature		$T_{opr}$	-30 to +100	°C
Storage temperature		$T_{stg}$	-55 to +125	°C

\*1 Pulse width  $\leq 100 \mu s$ , repeat 100 pps

\*2 Input power derating ratio is 0.75 mW/°C at  $T_a \geq 25^\circ C$ .

\*3 Output power derating ratio is 1.5 mW/°C at  $T_a \geq 25^\circ C$ .

### ■ Electrical Characteristics (Ta = 25°C)

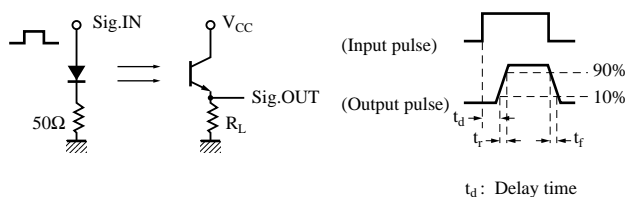
Parameter		Symbol	Conditions	min	typ	max	Unit
Input characteristics	Reverse current (DC)	$I_R$	$V_R = 3V$			10	$\mu A$
	Forward voltage (DC)	$V_F$	$I_F = 50mA$		1.35	1.5	V
	Capacitance between pins	$C_t$	$V_R = 0V, f = 1MHz$		15		pF
Output characteristics	Collector cutoff current	$I_{CEO}$	$V_{CE} = 20V$		5	100	nA
	Collector to emitter voltage	$V_{CEO}$	$I_C = 100\mu A$	80			V
	Collector to emitter capacitance	$C_C$	$V_{CE} = 10V, f = 1MHz$		3		pF
	Emitter to collector voltage	$V_{ECO}$	$I_E = 10\mu A$	7			V
Transfer characteristics	DC current transfer ratio	$CTR^{*1, *5}$	$V_{CE} = 5V, I_F = 5mA$	100		600	%
	Isolation voltage, input to output	$V_{ISO}$	$t = 1 min., RH < 60\%$	5000			$V_{rms}$
	Isolation capacitance, input to output	$C_{ISO}$	$f = 1MHz$		0.7		pF
	Isolation resistance, input to output	$R_{ISO}$	$V_{ISO} = 500V$	$10^{11}$			$\Omega$
	Rise time	$t_r^{*2, *4}$	$V_{CC} = 10V, I_C = 2mA$		2		$\mu s$
	Fall time	$t_f^{*3, *4}$	$R_L = 100\Omega$		3		$\mu s$
	Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_F = 20mA, I_C = 1mA$		0.1	0.2	V

\*1 DC current transfer ratio (CTR) is a ratio of output current against DC input current.

\*2  $t_r$ : Time required for the collector current to increase from 10% to 90% of its final value

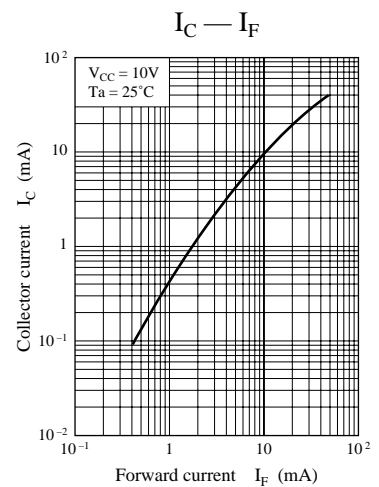
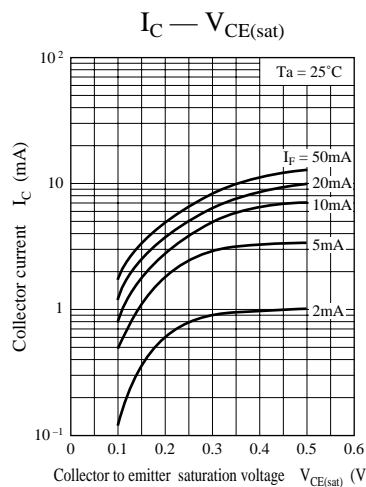
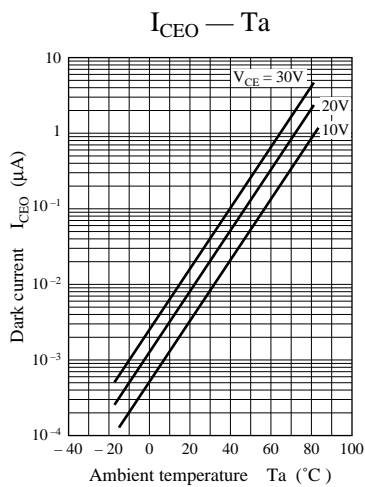
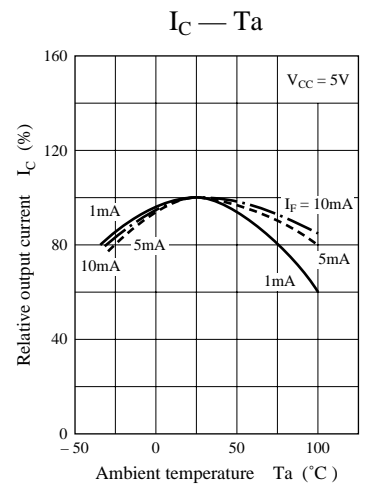
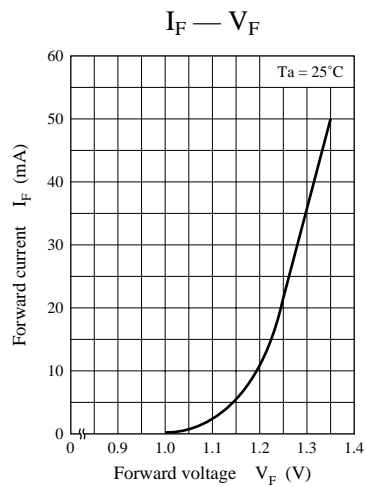
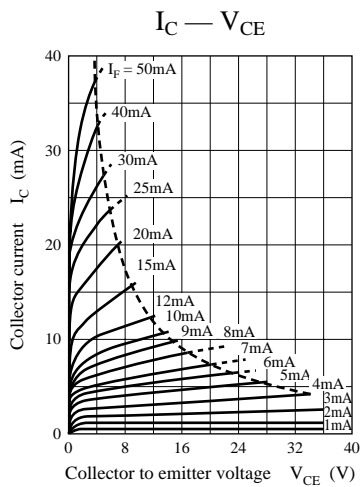
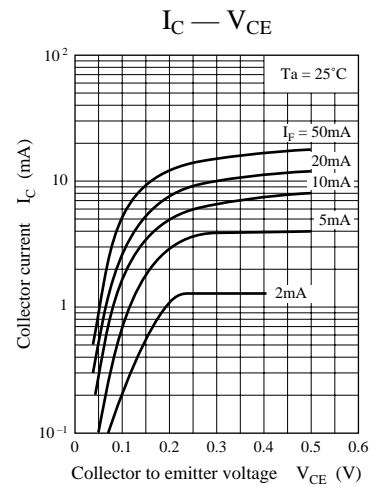
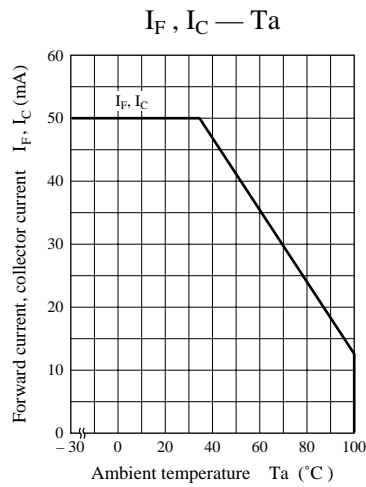
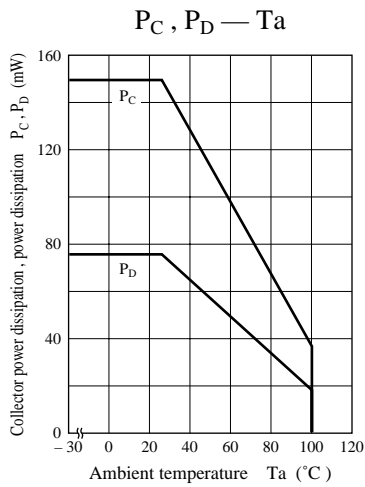
\*3  $t_f$ : Time required for the collector current to decrease from 90% to 10% of its initial value

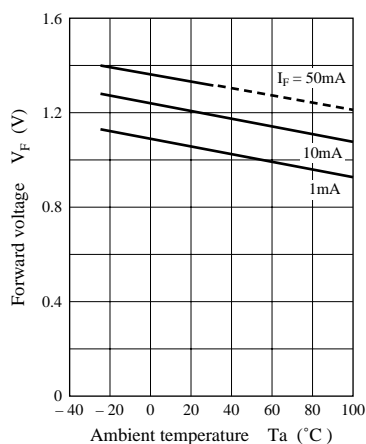
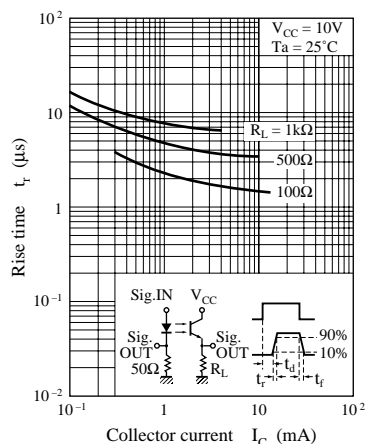
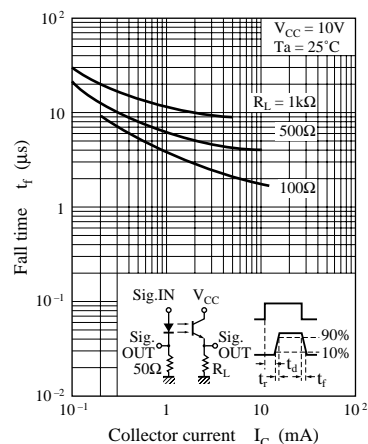
\*4 Rise and fall time measurement circuit



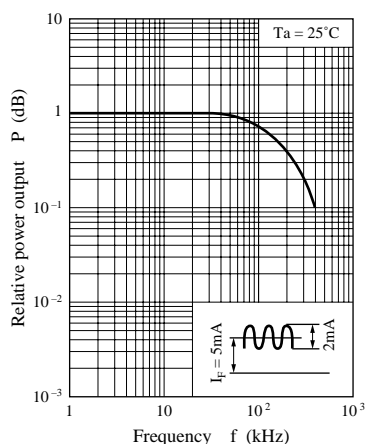
\*5 CTR classifications

Class	General	R	S
CTR (%)	100 to 600	100 to 300	200 to 600

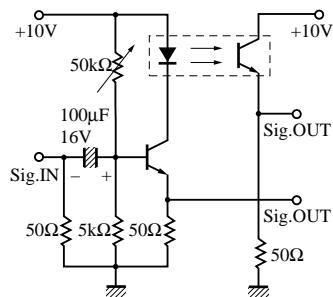


$V_F - T_a$  $t_r - I_C$  $t_f - I_C$ 

Frequency characteristics



Measurement circuit of frequency characteristics



# Caution for Safety

 **DANGER**

Gallium arsenide material (GaAs) is used in this product.

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